

74LVT374

3.3 V octal D-type flip-flop; 3-state

Rev. 4 — 22 November 2011

Product data sheet

1. General description

The 74LVT374 is a high-performance product designed for V_{CC} operation at 3.3 V.

This device is an 8-bit, edge triggered register coupled to eight 3-state output buffers. The two sections of the device are controlled independently by the clock (pin CP) and output enable (pin \overline{OE}) control gates. The state of each Dn input (one setup time before the LOW-to-HIGH clock transition) is transferred to the corresponding flip-flops Qn output.

The 3-state output buffers are designed to drive heavily loaded 3-state buses, MOS memories, or MOS microprocessors.

The active LOW output enable (pin \overline{OE}) controls all eight 3-state buffers independent of the clock operation.

When pin \overline{OE} is LOW, the stored data appears at the outputs. When pin \overline{OE} is HIGH, the outputs are in the high-impedance OFF-state, which means they will neither drive nor load the bus.

2. Features and benefits

- Inputs and outputs arranged for easy interfacing to microprocessors
- 3-state outputs for bus interfacing
- Common output enable control
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Power-up reset
- Power-up 3-state
- Latch-up protection
 - ◆ JESD78 class II exceeds 500 mA
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$



3. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|-------------|-------------------|---------|--|----------|
| | Temperature range | Name | Description | |
| 74LVT374D | -40 °C to +85 °C | SO20 | plastic small outline package; 20 leads; body width 7.5 mm | SOT163-1 |
| 74LVT374DB | -40 °C to +85 °C | SSOP20 | plastic shrink small outline package; 20 leads; body width 5.3 mm | SOT339-1 |
| 74LVT374PW | -40 °C to +85 °C | TSSOP20 | plastic thin shrink small outline package; 20 leads; body width 4.4 mm | SOT360-1 |

4. Functional diagram

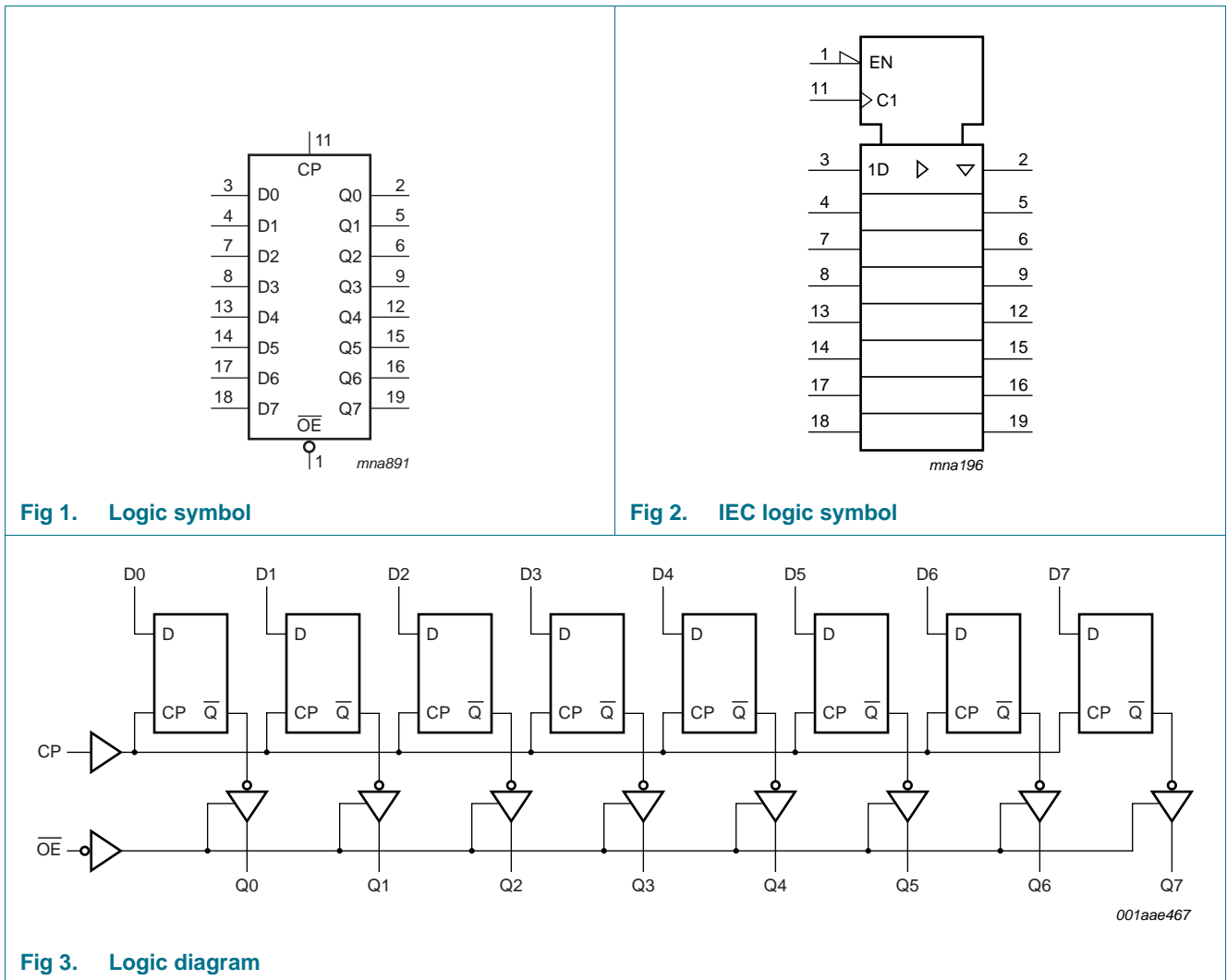


Fig 1. Logic symbol

Fig 2. IEC logic symbol

Fig 3. Logic diagram

5. Pinning information

5.1 Pinning

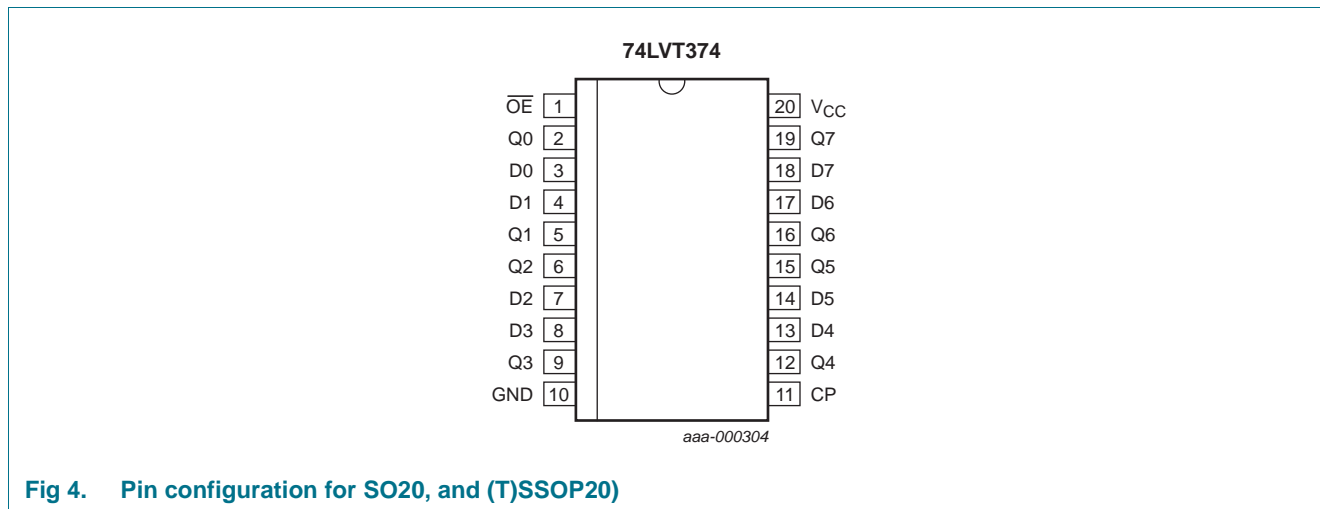


Fig 4. Pin configuration for SO20, and (T)SSOP20)

5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|----------------------------|--|
| \overline{OE} | 1 | output enable input (active LOW) |
| D0 to D7 | 3, 4, 7, 8, 13, 14, 17, 18 | data input |
| GND | 10 | ground (0 V) |
| CP | 11 | clock pulse input (active rising edge) |
| Q0 to Q7 | 2, 5, 6, 9, 12, 15, 16, 19 | data output |
| V _{CC} | 20 | supply voltage |

6. Functional description

6.1 Function table

Table 3. Function table [1]

| Operating mode | Control | | Input | Internal register | Output |
|------------------------|---------|--------|-------|-------------------|--------|
| | OE | CP | Dn | | Qn |
| Load and read register | L | ↑ | l | L | L |
| | | | h | H | H |
| Hold | L | NC | X | NC | NC |
| Disable outputs | H | L or H | X | NC | Z |
| | | ↑ | Dn | Dn | Z |

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 ↑ = LOW-to-HIGH clock transition;
 h = HIGH voltage level one setup time prior to the LOW-to-HIGH clock transition;
 l = LOW voltage level one setup time prior to the LOW-to-HIGH clock transition;
 Z = high-impedance OFF-state;
 NC = no change;
 X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-----------------------------------|----------|------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| V_I | input voltage | | [1] -0.5 | +7.0 | V |
| V_O | output voltage | output in OFF-state or HIGH-state | [1] -0.5 | +7.0 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | - | -50 | mA |
| I_{OK} | output clamping current | $V_O < 0$ V | - | -50 | mA |
| I_O | output current | output in LOW-state | - | 128 | mA |
| | | output in HIGH-state | - | -64 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | [2] - | 150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +85 °C | [3] - | 500 | mW |

- [1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
 [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.
 [3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.
 For SSOP20 and TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.
 For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-------------------------------------|---|-----|-----|--------------------|
| V_{CC} | supply voltage | | 2.7 | 3.6 | V |
| V_I | input voltage | | 0 | 5.5 | V |
| V_{IH} | HIGH-level input voltage | | 2.0 | - | V |
| V_{IL} | LOW-level input voltage | | - | 0.8 | V |
| I_{OH} | HIGH-level output current | | - | -32 | mA |
| I_{OL} | LOW-level output current | | - | 32 | mA |
| | | current duty cycle $\leq 50\%$; $f_i \geq 1$ kHz | - | 64 | mA |
| T_{amb} | ambient temperature | in free air | -40 | +85 | $^{\circ}\text{C}$ |
| $\Delta t/\Delta V$ | input transition rise and fall rate | outputs enabled | - | 10 | ns/V |

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | $T_{amb} = -40\text{ }^{\circ}\text{C to } +85\text{ }^{\circ}\text{C}$ | | | Unit |
|--------------|-----------------------------------|--|---|--------------------|-----------|---------------|
| | | | Min | Typ ^[1] | Max | |
| V_{IK} | input clamping voltage | $V_{CC} = 2.7\text{ V}; I_{IK} = -18\text{ mA}$ | -1.2 | -0.9 | - | V |
| V_{OH} | HIGH-level output voltage | $V_{CC} = 2.7\text{ V to } 3.6\text{ V}; I_{OH} = -100\text{ }\mu\text{A}$ | $V_{CC} - 0.2$ | $V_{CC} - 0.1$ | - | V |
| | | $V_{CC} = 2.7\text{ V}; I_{OH} = -8\text{ mA}$ | 2.4 | 2.5 | - | V |
| | | $V_{CC} = 3.0\text{ V}; I_{OH} = -32\text{ mA}$ | 2.0 | 2.2 | - | V |
| V_{OL} | LOW-level output voltage | $V_{CC} = 2.7\text{ V}$ | | | | |
| | | $I_{OL} = 100\text{ }\mu\text{A}$ | - | 0.1 | 0.2 | V |
| | | $I_{OL} = 24\text{ mA}$ | - | 0.3 | 0.5 | V |
| | | $V_{CC} = 3.0\text{ V}$ | | | | |
| | | $I_{OL} = 16\text{ mA}$ | - | 0.25 | 0.4 | V |
| | | $I_{OL} = 32\text{ mA}$ | - | 0.3 | 0.5 | V |
| $V_{OL(pu)}$ | power-up LOW-level output voltage | $V_{CC} = 3.6\text{ V}; I_O = 1\text{ mA}; V_I = \text{GND or } V_{CC}$ ^[2] | - | 0.13 | 0.55 | V |
| | | $I_{OL} = 64\text{ mA}$ | - | 0.4 | 0.55 | V |
| I_I | input leakage current | all input pins; $V_{CC} = 0\text{ V or } 3.6\text{ V}; V_I = 5.5\text{ V}$ | - | 1 | 10 | μA |
| | | control pins; $V_{CC} = 3.6\text{ V}; V_I = V_{CC}$ or GND | - | ± 0.1 | ± 1 | μA |
| | | data pins; $V_{CC} = 3.6\text{ V}$ ^[3] | | | | |
| | | $V_I = V_{CC}$ | - | 0.1 | 1 | μA |
| I_{OFF} | power-off leakage current | $V_{CC} = 0\text{ V}; V_I$ or $V_O = 0\text{ V to } 4.5\text{ V}$ | - | 1 | ± 100 | μA |
| | | $V_O = 5.5\text{ V and } V_{CC} = 3.0\text{ V};$ output HIGH ^[4] | - | 60 | 125 | μA |
| I_{BHL} | bus hold LOW current | $V_{CC} = 3.0\text{ V}; V_I = 0.8\text{ V}$ | 75 | 150 | - | μA |
| I_{BHH} | bus hold HIGH current | $V_{CC} = 3.0\text{ V}; V_I = 2.0\text{ V}$ ^[4] | - | -150 | -75 | μA |
| I_{BHHO} | bus hold HIGH overdrive current | $V_{CC} = 3.6; V_I = 0\text{ V to } 3.6\text{ V}$ ^[4] | - | - | 500 | μA |

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | | Unit | |
|-----------------------|------------------------------------|--|-------------------------------------|--------------------|------|---------|----|
| | | | Min | Typ ^[1] | Max | | |
| I _{BHLO} | bus hold LOW overdrive current | V _{CC} = 3.6; V _I = 0 V to 3.6 V | -500 | - | - | μA | |
| I _{O(pu/pd)} | power-up/power-down output current | V _{CC} ≤ 1.2 V; V _O = 0.5 V to V _{CC} ; V _I = GND or V _{CC} ; OE = don't care | [5] | - | 1 | ±100 μA | |
| I _{OZ} | OFF-state output current | V _{CC} = 3.6 V; V _I = V _{IH} or V _{IL} | | | | | |
| | | output HIGH: V _O = 3.0 V | - | 1 | 5 | μA | |
| | | output LOW: V _O = 0.5 V | -5 | 1 | - | μA | |
| I _{CC} | supply current | V _{CC} = 3.6 V; V _I = GND or V _{CC} ; I _O = 0 A | | | | | |
| | | outputs HIGH | - | 0.13 | 0.19 | mA | |
| | | outputs LOW | - | 3 | 12 | mA | |
| | | outputs disabled | [6] | - | 0.13 | 0.19 | mA |
| ΔI _{CC} | additional supply current | per input pin; V _{CC} = 3 V to 3.6 V; one input at V _{CC} - 0.6 V and other inputs at V _{CC} or GND | [7] | - | 0.1 | 0.2 | mA |
| C _I | input capacitance | V _I = 0 V or 3.0 V | - | 4 | - | pF | |
| C _O | output capacitance | outputs disabled; V _O = 0 V or 3.0 V | - | 7 | - | pF | |

- [1] Typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.
- [2] For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
- [3] Unused pins at V_{CC} or GND.
- [4] This is the bus hold overdrive current required to force the input to the opposite logic state.
- [5] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 3.3 V ± 0.3 V a transition time of 100 μs is permitted. This parameter is valid for T_{amb} = 25 °C only.
- [6] I_{CC} is measured with outputs pulled to V_{CC} or GND.
- [7] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to ground (GND = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | | Unit |
|------------------|-------------------------------------|---|-------------------------------------|--------------------|-----|------|
| | | | Min | Typ ^[1] | Max | |
| t _{PLH} | LOW to HIGH propagation delay | CP to Qn; see Table 6 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.7 | 3.2 | 5.1 | ns |
| | | V _{CC} = 2.7 V | - | - | 5.8 | ns |
| t _{PHL} | HIGH to LOW propagation delay | CP to Qn; see Table 6 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 2.2 | 3.5 | 5.2 | ns |
| | | V _{CC} = 2.7 V | - | - | 5.5 | ns |
| t _{PZH} | OFF-state to HIGH propagation delay | \overline{OE} to Qn; see Figure 6 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.5 | 3.2 | 5.3 | ns |
| | | V _{CC} = 2.7 V | - | - | 7.3 | ns |

Table 7. Dynamic characteristics ...continued

Voltages are referenced to ground (GND = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | | Unit |
|------------------|-------------------------------------|--|-------------------------------------|--------------------|-----|------|
| | | | Min | Typ ^[1] | Max | |
| t _{PZL} | OFF-state to LOW propagation delay | \overline{OE} to Qn; see Figure 7 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | 3.4 | 5.2 | ns |
| | | V _{CC} = 2.7 V | - | - | 6.1 | ns |
| t _{PHZ} | HIGH to OFF-state propagation delay | \overline{OE} to Qn; see Figure 6 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.9 | 4.3 | 6.7 | ns |
| | | V _{CC} = 2.7 V | - | - | 7.1 | ns |
| t _{PLZ} | LOW to OFF-state propagation delay | \overline{OE} to Qn; see Figure 7 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | 3.4 | 5.1 | ns |
| | | V _{CC} = 2.7 V | - | - | 5.1 | ns |
| t _{su} | set-up time | Dn to CP; see Figure 8 ^[2] | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | 0.7 | - | ns |
| | | V _{CC} = 2.7 V | 2.0 | - | - | ns |
| t _h | hold time | Dn to CP; see Figure 8 ^[3] | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 0.3 | -0.5 | - | ns |
| | | V _{CC} = 2.7 V | 0 | - | - | ns |
| t _w | pulse width | CP input HIGH; see Figure 5 ^[4] | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.5 | 0.8 | - | ns |
| | | V _{CC} = 2.7 V | 1.5 | - | - | ns |
| | | CP input LOW; see Figure 5 ^[4] | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 2.5 | 1.7 | - | ns |
| | | V _{CC} = 2.7 V | 3.0 | - | - | ns |
| f _{max} | maximum frequency | CP input; see Figure 5 | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 125 | 200 | - | MHz |
| | | V _{CC} = 2.7 V | 125 | - | - | MHz |

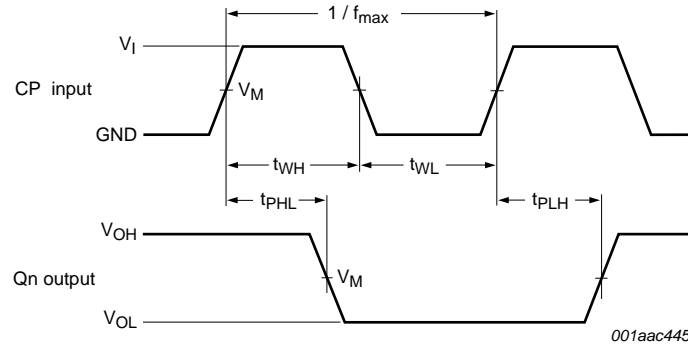
[1] Typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

[2] t_{su} is the same as t_{su(H)} and t_{su(L)}

[3] t_h is the same as t_{h(H)} and t_{h(L)}

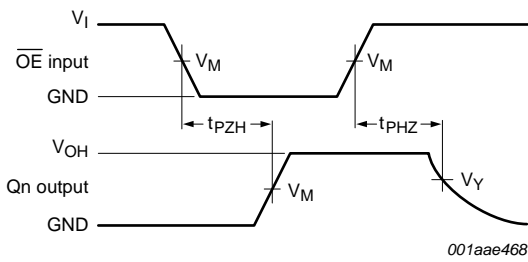
[4] t_w is the same as t_{wH} and t_{wL}

11. Waveforms



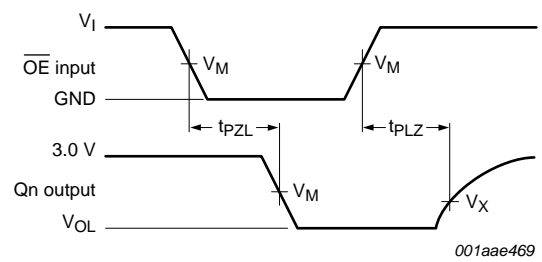
Measurement points are given in [Table 8](#)
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. Propagation delay clock input (CP) to output (Qn), pulse width clock (CP) and maximum clock frequency



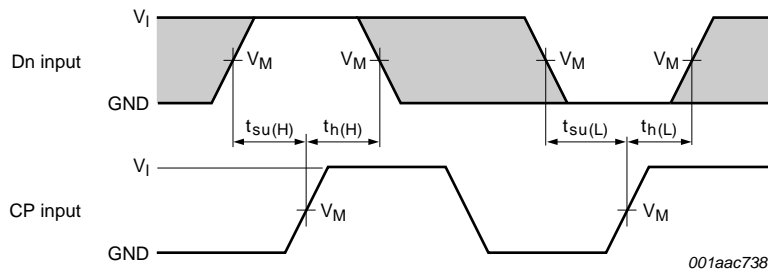
Measurement points are given in [Table 8](#)
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. Output enable time to HIGH-state and output disable time from HIGH-state



Measurement points are given in [Table 8](#)
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 7. Output enable time to LOW-state and output disable time from LOW-state

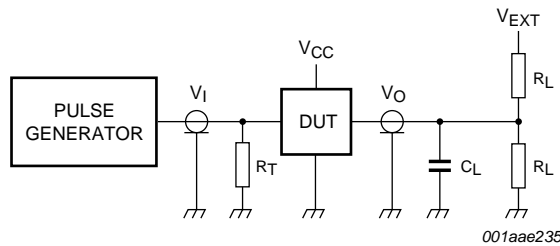
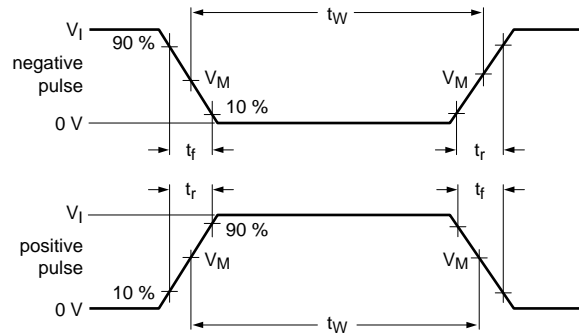


Measurement points are given in [Table 8](#)
Remark: The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig 8. Data setup and hold times

Table 8. Measurement points

| Input | Output | | |
|-------|--------|------------------|------------------|
| V_M | V_M | V_X | V_Y |
| 1.5 V | 1.5 V | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |



Test data is given in [Table 9](#).

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = Test voltage for switching times.

Fig 9. Load circuitry for switching times

Table 9. Test data

| Input | | | | Load | | V_{EXT} | | |
|-------|---------------|--------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| V_I | f_i | t_W | t_r, t_f | C_L | R_L | t_{PHZ}, t_{PZH} | t_{PLZ}, t_{PZL} | t_{PLH}, t_{PHL} |
| 2.7 V | ≤ 10 MHz | 500 ns | ≤ 2.5 ns | 50 pF | 500 Ω | GND | 6 V | open |

12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

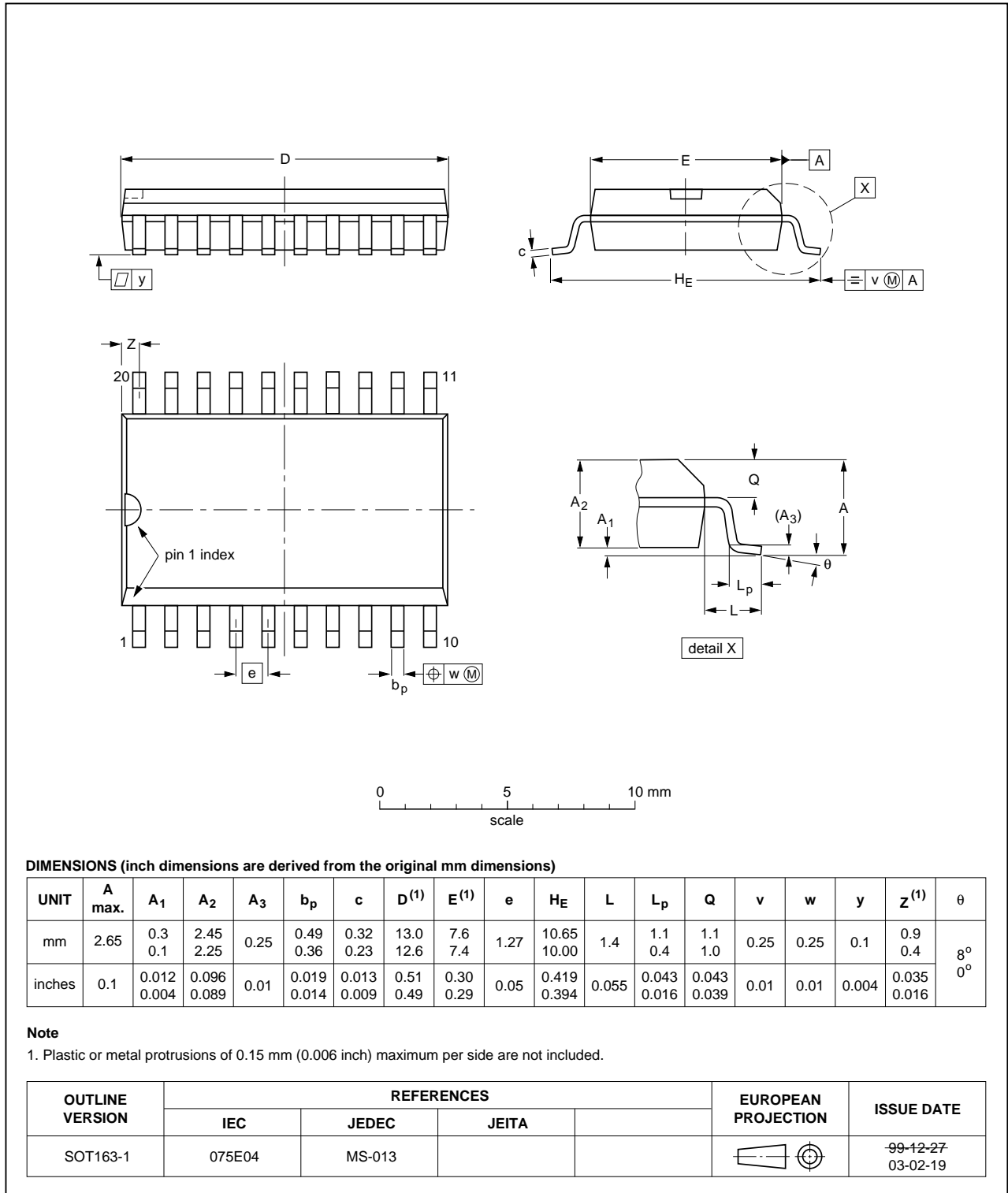


Fig 10. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

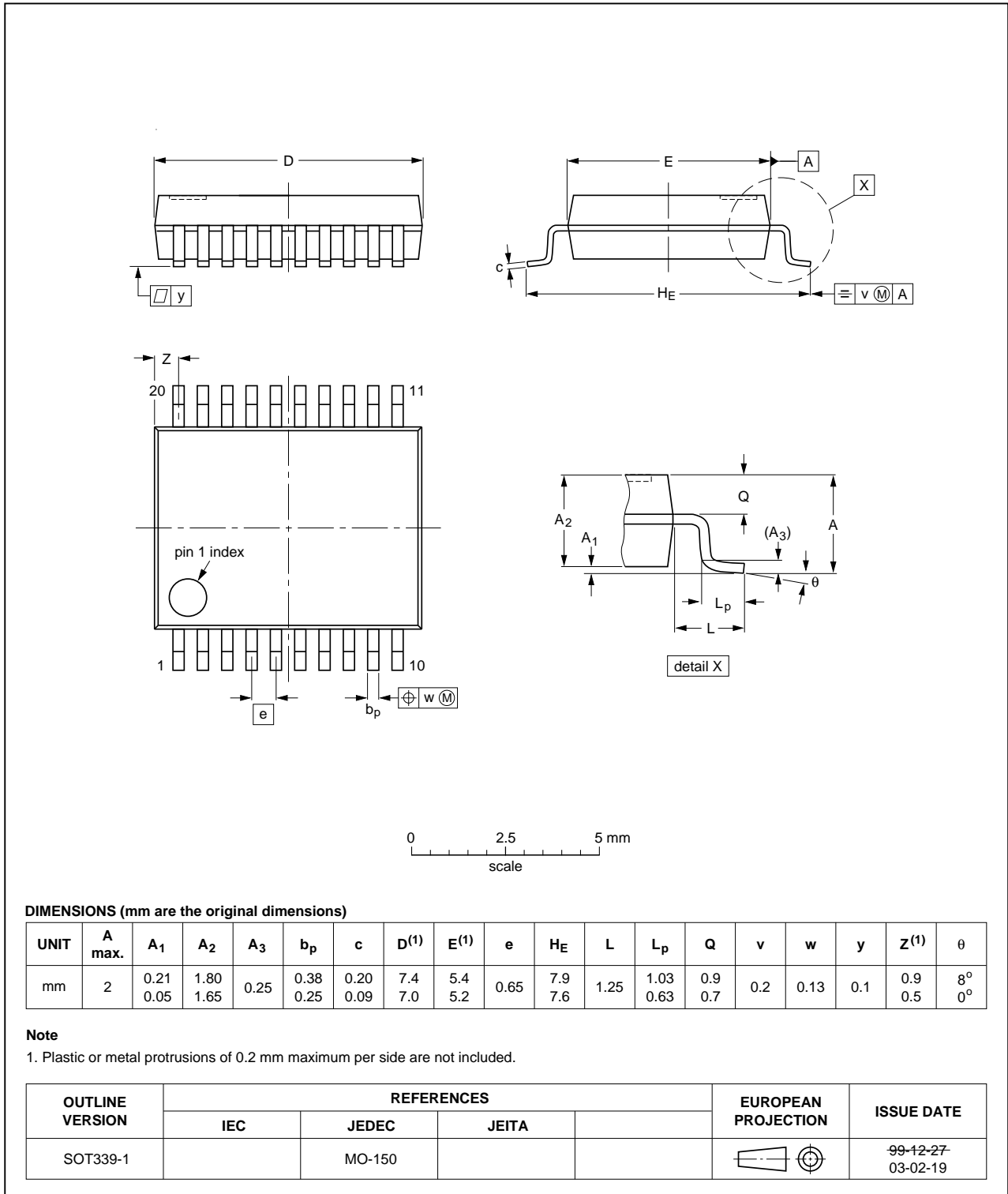


Fig 11. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

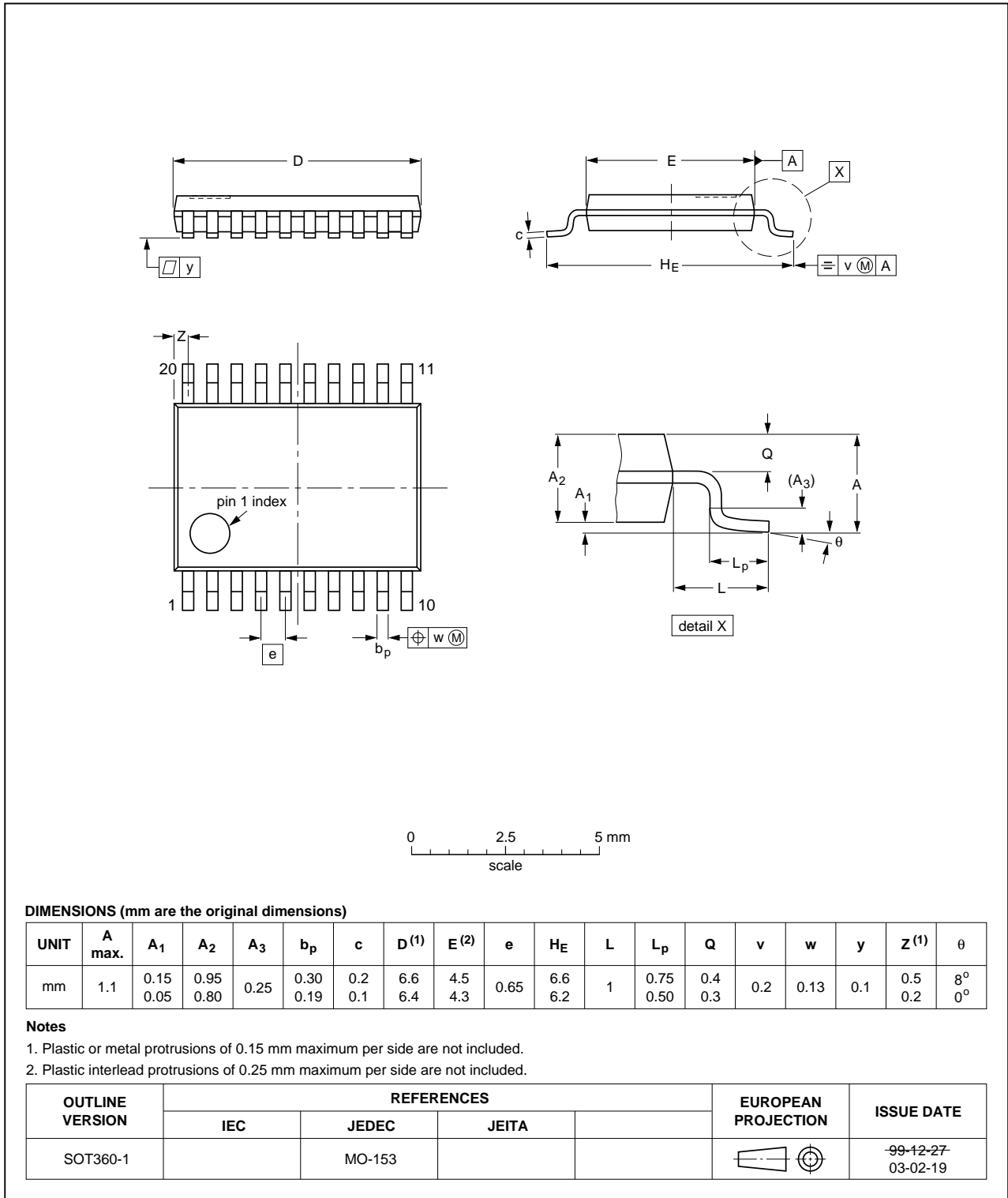


Fig 12. Package outline SOT360-1 (TSSOP20)

13. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| MOS | Metal Oxide Semiconductor |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|-----------------------|---------------|--------------|
| 74LVT374 v.4 | 20111122 | Product data sheet | - | 74LVT374 v.3 |
| Modifications: | <ul style="list-style-type: none">Legal pages updated. | | | |
| 74LVT374 v.3 | 20110914 | Product data sheet | - | 74LVT374 v.2 |
| 74LVT374 v.2 | 19980219 | product specification | - | 74LVT374 v.1 |
| 74LVT374 v.1 | 19960208 | product specification | - | - |

15. Legal information

15.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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